



DONGGUAN NANJING ELECTRONICS LTD.,

SMC Plastic-Encapsulate Diodes

ES5A THRU ES5K Super Fast Recovery Rectifier Diodes

Features

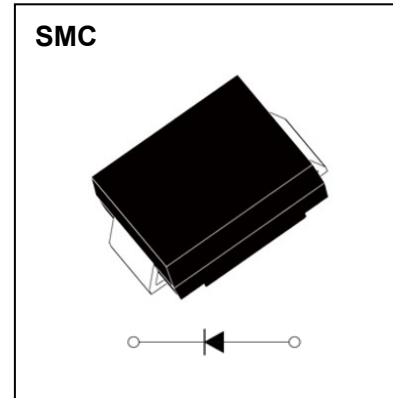
- $I_{F(AV)}$ 5A
- V_{RRM} 50V-600V
- High surge current capability
- Polarity: Color band denotes cathode

Applications

- Rectifier

Marking

- ES5X
- X : From A To K



Limiting Values(Absolute Maximum Rating)

Item	Symbol	Unit	Test Conditions	ES5							
				A	B	C	D	E	G	J	K
Repetitive Peak Reverse Voltage	V_{RRM}	V		50	100	150	200	300	400	600	800
Maximum RMS Voltage	V_{RMS}	V		35	70	105	140	210	280	420	560
Average Forward Current	$I_{F(AV)}$	A	60Hz Half-sine wave, Resistance load, $T_L = 125^\circ\text{C}$	5.0							
Surge(Non-repetitive)Forward Current	I_{FSM}	A	60Hz Half-sine wave, 1 cycle, $T_a = 25^\circ\text{C}$	150							
Operation Junction and Storage Temperature Range	T_J, T_{STG}	$^\circ\text{C}$		-55 ~ +150							

Electrical Characteristics ($T=25^\circ\text{C}$ Unless otherwise specified)

Item	Symbol	Unit	Test Condition	ES5								
				A	B	C	D	E	G	J	K	
Peak Forward Voltage	V_F	V	$I_F = 5.0\text{A}$	0.95			1.25		1.65			
Maximum reverse recovery time	t_{rr}	ns	$I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{rr} = 0.25\text{A}$	35								45
Peak Reverse Current	I_{RRM1}	μA	$V_{RM} = V_{RRM}$	$T_a = 25^\circ\text{C}$			5					
	I_{RRM2}			$T_a = 100^\circ\text{C}$			500					
Thermal Resistance(Typical)	$R_{\theta J-A}$	$^\circ\text{C}/\text{W}$	Between junction and ambient				42					
	$R_{\theta J-L}$		Between junction and terminal				12					

Notes:

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.30" x 0.30" (8.0 mm x 8.0 mm) copper pad areas

Typical Characteristics

FIG.1: FORWARD CURRENT DERATING CURVE

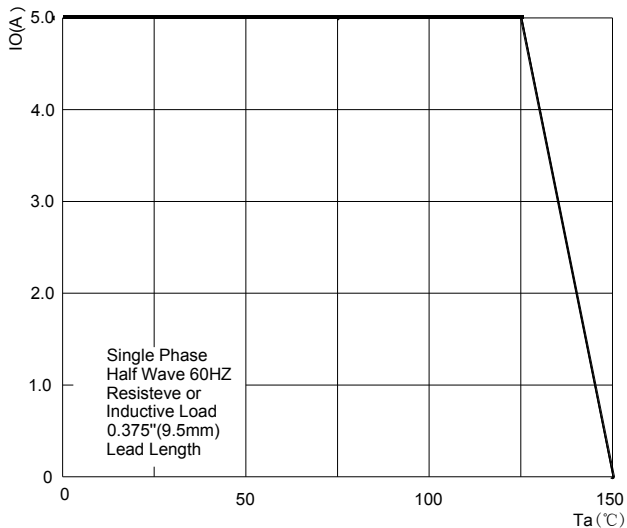
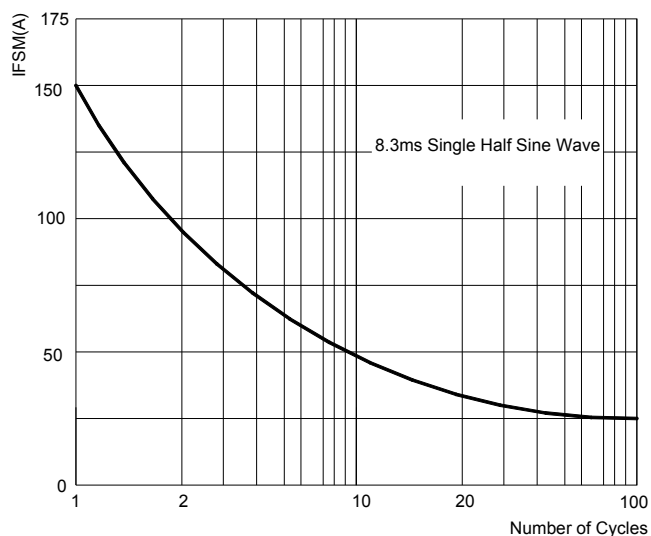


FIG.2: MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT



TYPICAL FORWARD CHARACTERISTICS

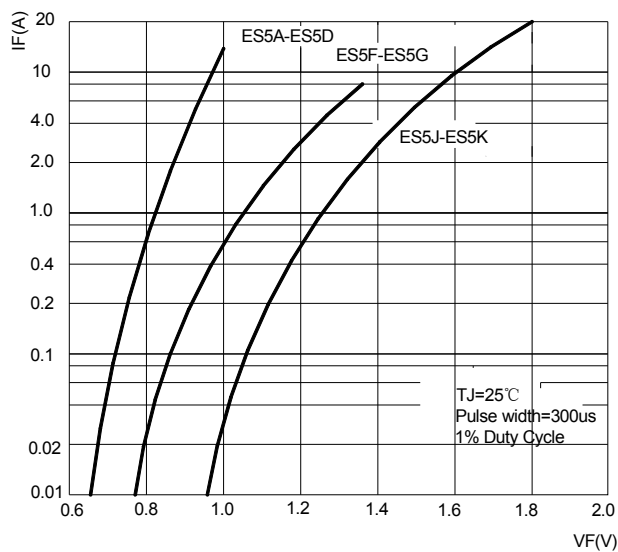
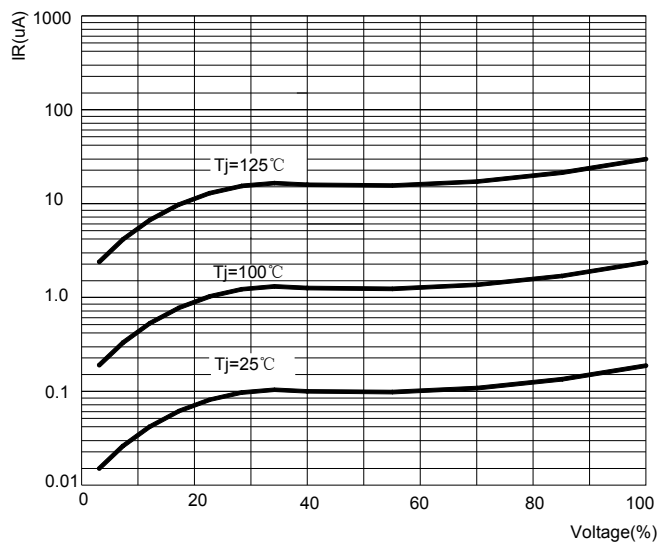


FIG.4: TYPICAL REVERSE CHARACTERISTICS



Typical Characteristics

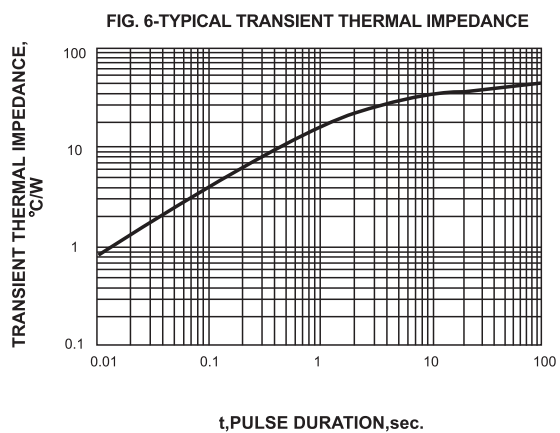
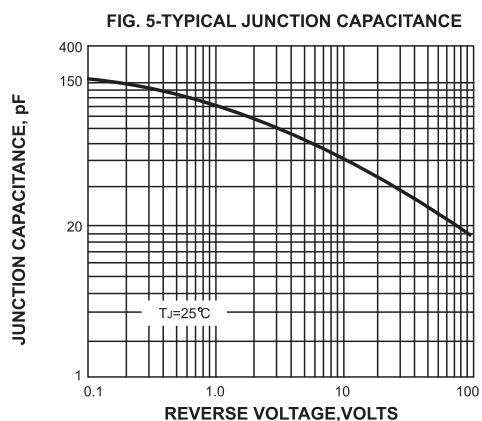
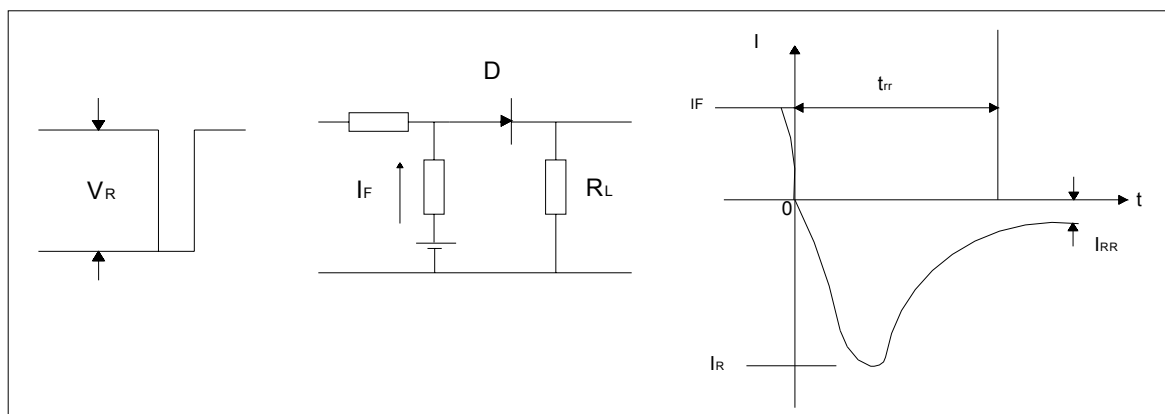
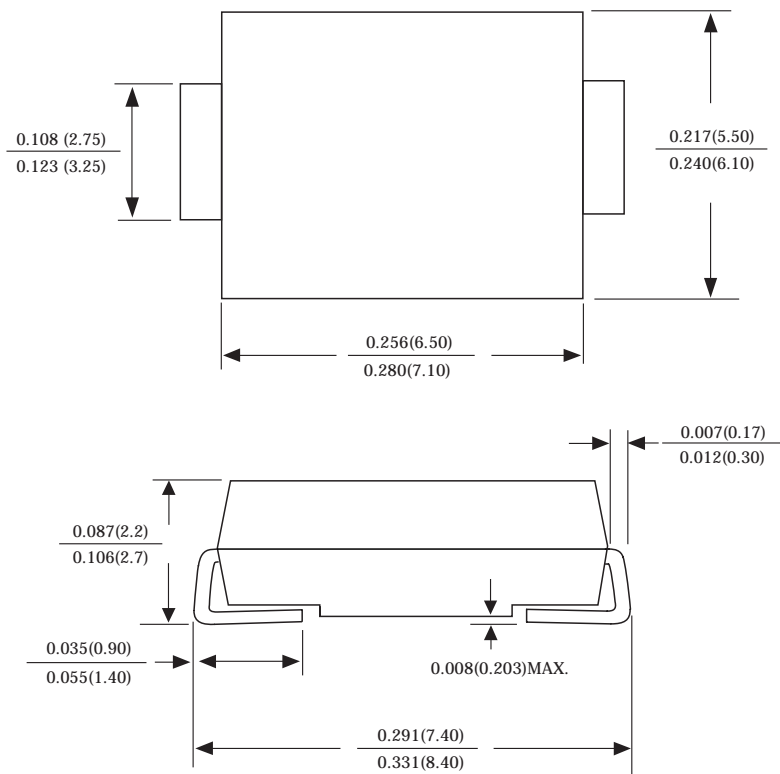


FIG. 7: Diagram of circuit and Testing wave form of reverse recovery time

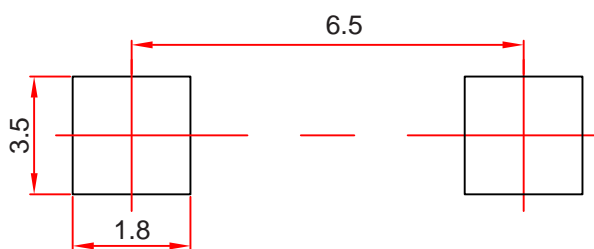


SMC Package Outline Dimensions



Dimensions in inches and (millimeters)

SMC Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

Reel Taping Specifications For Surface Mount Devices–SMC

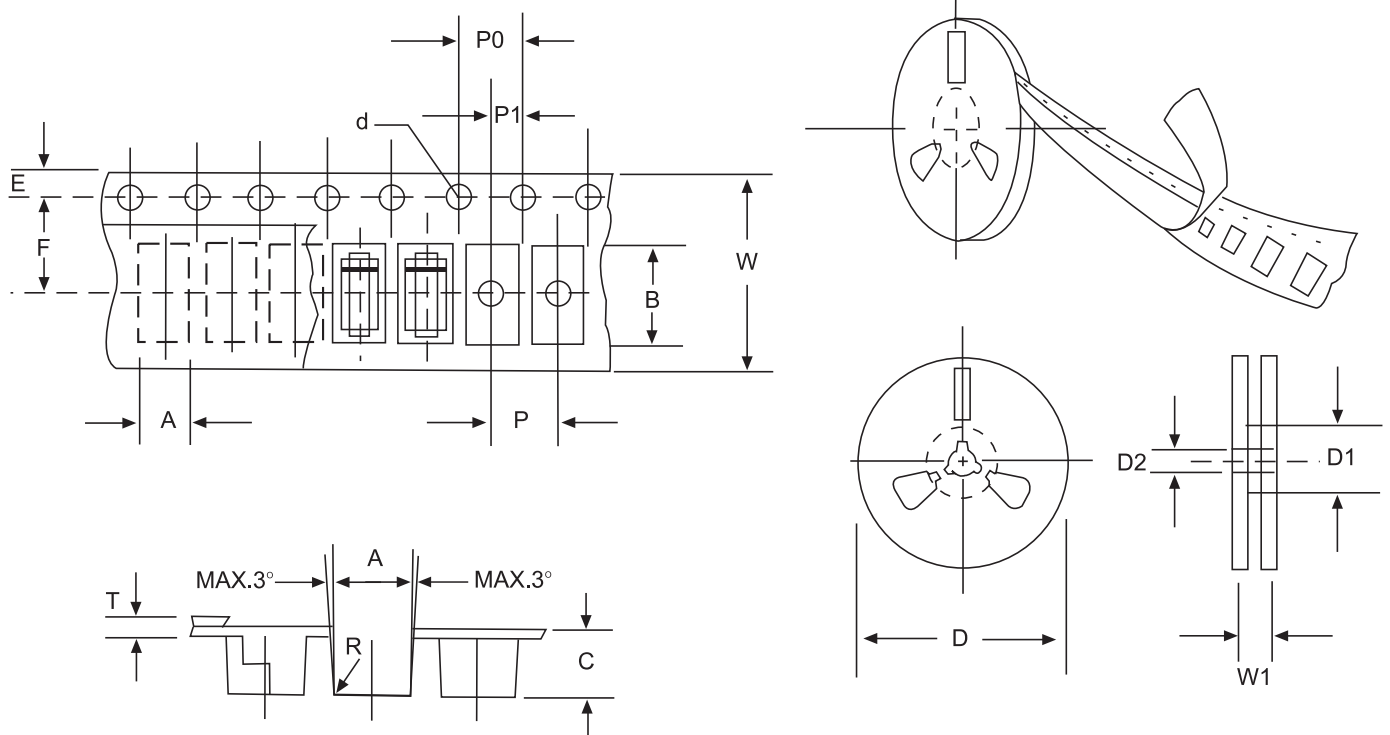


FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	SMC mm(inch)
Carrier width	A	6.05±0.1(0.238±0.004)
Carrier length	B	8.31±0.1(0.327±0.004)
Carrier depth	C	2.70±0.1(0.106±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	330±2.0(13±0.079)
Reel inner diameter	D1	75 ±1.0 (2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Strocket hole position	E	1.75 ±0.1(0.069±0.004)
Punch hole position	F	7.65±0.05(0.301±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Total tape thickness	T	0.3 ± 0.1 (0.012±0.004)
Tape width	W	16.0±0.2(0.630±0.008)
Reel width	W1	24.0±2.0(0.945±0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.